# **Quad 2-Input OR Gate**

# **Features**

- Outputs Source/Sink 24 mA
- 'ACT32 Has TTL Compatible Inputs
- Pb-Free Packages are Available\*

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# **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
DC Supply Voltage (Referenced to GND)	V <sub>CC</sub>	-0.5 to +7.0	V
DC Input Voltage (Referenced to GND)	V <sub>in</sub>	-0.5 to V <sub>CC</sub> +0.5	V
DC Output Voltage (Referenced to GND)	V <sub>out</sub>	-0.5 to V <sub>CC</sub> +0.5	٧
DC Input Current, per Pin	I <sub>in</sub>	±20	mA
DC Output Sink/Source Current, per Pin	I <sub>out</sub>	±50	mA
DC V <sub>CC</sub> or GND Current per Output Pin	I <sub>CC</sub>	±50	mA
Storage Temperature	T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



PDIP-14 N SUFFIX CASE 646



SOIC-14 D SUFFIX CASE 751A



TSSOP-14 DT SUFFIX CASE 948G



SOEIAJ-14 M SUFFIX CASE 965

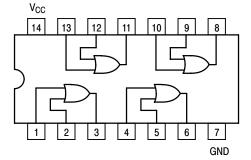


Figure 1. Pinout: 14-Lead Packages Conductors (Top View)

# **DEVICE MARKING INFORMATION**

See specific marking information in the device marking section on page 5 of this data sheet.

# **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Тур	Max	Unit
	County Vallage	'AC	2.0	5.0	6.0	
V <sub>CC</sub>	Supply Voltage	'ACT	4.5	5.0	5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	_	150	-	
$t_r$ , $t_f$	t <sub>r</sub> , t <sub>f</sub> Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	_	40	-	ns/V
		V <sub>CC</sub> @ 5.5 V	_	25	-	
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	_	10	-	2011
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	_	8.0	-	ns/V
TJ	Junction Temperature (PDIP)		_	-	140	°C
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C
I <sub>OH</sub>	Output Current – High		_	-	-24	mA
I <sub>OL</sub>	Output Current - Low		-	-	24	mA

V<sub>in</sub> from 30% to 70% V<sub>CC</sub>; see individual Data Sheets for devices that differ from the typical input rise and fall times.
 V<sub>in</sub> from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

# **DC CHARACTERISTICS**

			74.	AC	74AC			
Symbol	Parameter	Parameter $ \begin{array}{c c} V_{CC} \\ (V) \end{array}  \begin{array}{c c} T_A = \\ T_A = +25^{\circ}C \end{array}  \begin{array}{c c} T_A = \\ -40^{\circ}C \ to \\ +85^{\circ}C \end{array} $		Parameter $V_{CC}$ $T_A = +25^{\circ}C$ $-40^{\circ}C$ to		–40°C to	Unit	Conditions
			Тур	Guar	anteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V	
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	Ι <sub>ΟUT</sub> = –50 μΑ	
		3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ $-12 \text{ mA}$ $I_{OH}$ $-24 \text{ mA}$ $-24 \text{ mA}$	
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I <sub>OUT</sub> = 50 μA	
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	V	$^{\star V_{\text{IN}} = V_{\text{IL}} \text{ or } V_{\text{IH}}}_{\text{12 mA}}$ $^{\text{IOL}}_{\text{OL}}  \text{24 mA}$ $^{\text{24 mA}}_{\text{24 mA}}$	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
Icc	Maximum Quiescent Supply Current	5.5	_	4.0	40	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND	

<sup>\*</sup>All outputs loaded; thresholds on input associated with output under test.

NOTE:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V  $V_{CC}$ .

<sup>†</sup>Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms - See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

			74AC			74AC			
Symbol	Parameter	V <sub>CC</sub> * (V)		Γ <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		T <sub>A</sub> = - to +8 C <sub>L</sub> = 8		Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.5	9.0 7.5	1.5 1.0	10.0 8.5	ns	3–5
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	1.5 1.5	7.0 5.0	8.5 7.0	1.0 1.0	9.0 7.5	ns	3–5

<sup>\*</sup>Voltage Range 3.3 V is 3.3 V  $\pm$ 0.3 V. Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

# **DC CHARACTERISTICS**

			74	CT	74ACT		
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V <sub>OUT</sub> = 0.1 V or V <sub>CC</sub> – 0.1 V
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	$^*V_{IN} = V_{IL} \text{ or } V_{IH}$ $^{-24} \text{ mA}$ $^{1}_{OH}$ $^{-24} \text{ mA}$
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		4.5 5.5	_ _	0.36 0.36	0.44 0.44	V	$^*V_{IN} = V_{IL} \text{ or } V_{IH}$ $^{IOL}$ $^{IOL}$ $^{IOL}$ $^{IOL}$ $^{IOL}$
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V <sub>I</sub> = V <sub>CC</sub> , GND
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	_	1.5	mA	V <sub>I</sub> = V <sub>CC</sub> – 2.1 V
I <sub>OLD</sub>	†Minimum Dynamic Output Current	5.5	-	_	75	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>		5.5	-	_	-75	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	-	4.0	40	μΑ	V <sub>IN</sub> = V <sub>CC</sub> or GND

<sup>\*</sup>All outputs loaded; thresholds on input associated with output under test.

<sup>†</sup>Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS (For Figures and Waveforms – See Section 3 of the ON Semiconductor FACT Data Book, DL138/D)

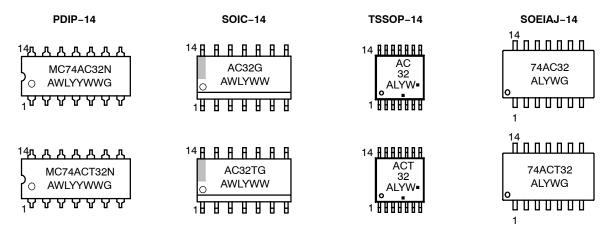
		74ACT V <sub>CC</sub> * T <sub>A</sub> = +25°C			74A	СТ			
Symbol	Parameter	V <sub>CC</sub> * (V)		Γ <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		T <sub>A</sub> = to +8: C <sub>L</sub> = 5	5°C	Unit	Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–6
t <sub>PHL</sub>	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–6

<sup>\*</sup>Voltage Range 5.0 V is 5.0 V ±0.5 V.

# CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	20	pF	V <sub>CC</sub> = 5.0 V

# **MARKING DIAGRAMS**



A = Assembly Location L, WL = Wafer Lot

Y, YY = Year
W, WW = Work Week
G = Pb-Free Package
= Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

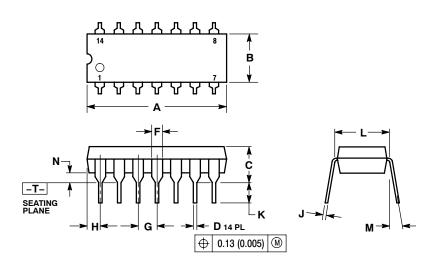
Device	Package	Shipping <sup>†</sup>	
MC74AC32N	PDIP-14		
MC74AC32NG	PDIP-14 (Pb-Free)	or Usite ( Deil	
MC74ACT32N	PDIP-14	25 Units / Rail	
MC74ACT32NG	PDIP-14 (Pb-Free)		
MC74AC32D	SOIC-14		
MC74AC32DG	SOIC-14 (Pb-Free)	55 Units / Rail	
MC74AC32DR2	SOIC-14		
MC74AC32DR2G	SOIC-14 (Pb-Free)	2500 Units / Reel	
MC74ACT32D	SOIC-14		
MC74ACT32DG	SOIC-14 (Pb-Free)	55 Units / Rail	
MC74ACT32DR2	SOIC-14		
MC74ACT32DR2G	SOIC-14 (Pb-Free)		
MC74AC32DTR2	TSSOP-14*	2500 Units / Reel	
MC74AC32DTR2G	TSSOP-14*		
MC74ACT32DTR2	TSSOP-14*		
MC74ACT32DTR2G	TSSOP-14*		
MC74AC32MEL	SOEIAJ-14		
MC74AC32MELG	SOEIAJ-14 (Pb-Free)	0000 Heite / Deel	
MC74ACT32MEL	SOEIAJ-14	2000 Units / Reel	
MC74ACT32MELG	SOEIAJ-14 (Pb-Free)		

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>This package is inherently Pb-Free.

# **PACKAGE DIMENSIONS**

PDIP-14 CASE 646-06 **ISSUE P** 

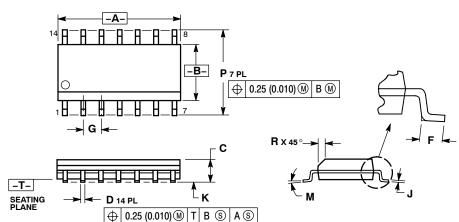


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.715	0.770	18.16	19.56
В	0.240	0.260	6.10	6.60
С	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100	100 BSC 2		BSC
Н	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
М		10 °		10 °
N	0.015	0.039	0.38	1.01

# **PACKAGE DIMENSIONS**

SOIC-14 CASE 751A-03 ISSUE H



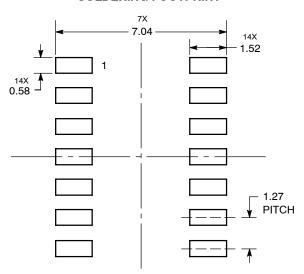
#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- 1. DIMENSIONING AND TOLEHANGING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

  2. DIMENSION D. POCE NOT INCLUDE.
- PEH SIDE.
  5. DIMENSION D DOES NOT INCLUDE
  DAMBAR PROTRUSION. ALLOWABLE
  DAMBAR PROTRUSION SHALL BE 0.127
  (0.005) TOTAL IN EXCESS OF THE D
  DIMENSION AT MAXIMUM MATERIAL
  CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
O	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
ے	0.19	0.25	0.008	0.009
Κ	0.10	0.25	0.004	0.009
М	0 °	7 °	0°	7 °
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.010

# **SOLDERING FOOTPRINT\***

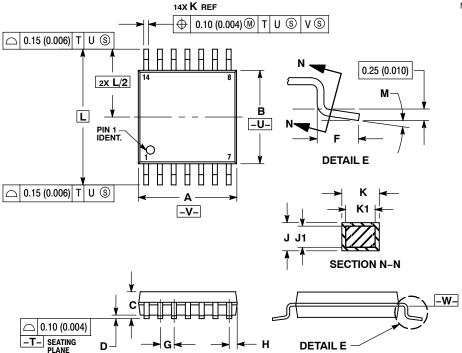


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## PACKAGE DIMENSIONS

TSSOP-14 CASE 948G-01 **ISSUE B** 



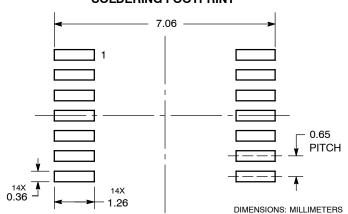
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

- CONTROLLING DIMENSION: MILLIMETER.
  DIMENSION A DOES NOT INCLUDE MOLD
  FLASH, PROTRUSIONS OR GATE BURRS.
  MOLD FLASH OR GATE BURRS SHALL NOT
  EXCEED 0.15 (0.006) PER SIDE.
  DIMENSION B DOES NOT INCLUDE
  INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION SHALL
  NOT EXCEED 0.25 (0.010) PER SIDE.
  DIMENSION K DOES NOT INCLUDE DAMBAR
  PROTRUSION, ALLOWABLE DAMBAR
  PROTRUSION, SHALL BE 0.08 (0.003) TOTAL
  IN EXCESS OF THE K DIMENSION AT IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
C		1.20		0.047
ם	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026	BSC
Η	0.50	0.60	0.020	0.024
7	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
Κ	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40	6.40 BSC		BSC
М	0 °	8 °	0 °	8 °

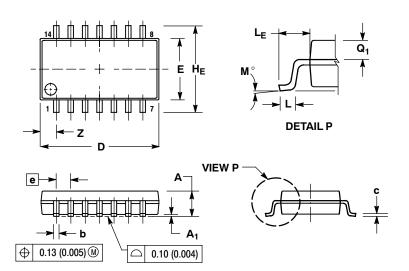
# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOEIAJ-14 CASE 965-01 **ISSUE A** 



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
- 2. CONTROLLING DIMENSION. MILLIMETER.
  3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- PEH SIDE.

  4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

  5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION, DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 ( 0.018).

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.10	0.20	0.004	0.008
D	9.90	10.50	0.390	0.413
Е	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050 BSC	
HE	7.40	8.20	0.291	0.323
0.50	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0°	10 °
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z		1.42		0.056

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